TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT process)

# 2SB907

Switching Applications
Hammer Drive, Pulse Motor Drive Applications
Power Amplifier Applications

- High DC current gain:  $h_{FE}$  (1) = 2000 (min) ( $V_{CE}$  = -2 V,  $I_{C}$  = -1 A)
- Low saturation voltage:  $V_{CE (sat)} = -1.5 \text{ V (max) (I}_{C} = -2 \text{ A)}$
- Complementary to 2SD1222.

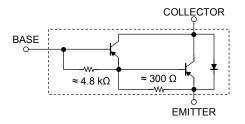
### Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V <sub>CBO</sub>	-60	٧	
Collector-emitter voltage		V <sub>CEO</sub>	-40	V	
Emitter-base voltage		V <sub>EBO</sub>	-5	<b>V</b>	
Collector current		I <sub>C</sub>	-3	Α	
Base current		Ι <sub>Β</sub>	-0.3	Α	
Collector power dissipation	Ta = 25°C	Pc	1.0	W	
	Tc = 25°C	1.0	15		
Junction temperature		Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	

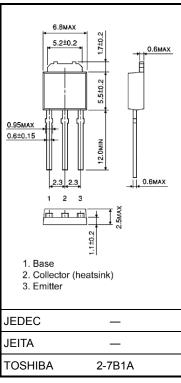
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

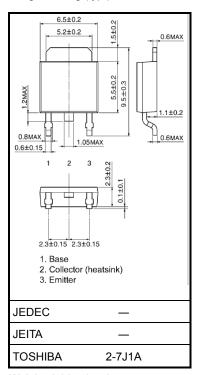
#### **Equivalent Circuit**



Unit: mm



Weight: 0.36 g (typ.)

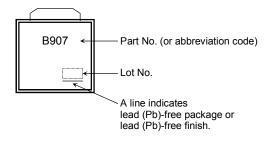


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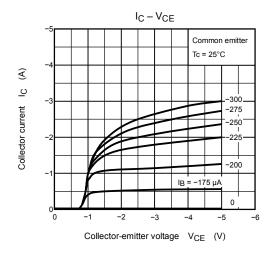
## Electrical Characteristics (Ta = 25°C)

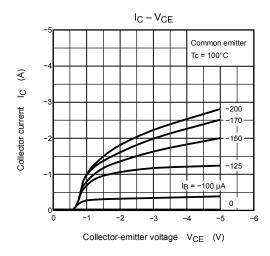
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off of	urrent	I <sub>CBO</sub>	V <sub>CB</sub> = -60 V, I <sub>E</sub> = 0	_	_	-20	μA
Emitter cut-off cu	rrent	I <sub>EBO</sub>	$V_{EB} = -5 \text{ V}, I_C = 0$	_	_	-2.5	mA
Collector-emitter	breakdown voltage	V (BR) CEO	$I_C = -25 \text{ mA}, I_B = 0$	-40	_	_	V
DC current gain		h <sub>FE (1)</sub>	V <sub>CE</sub> = -2 V, I <sub>C</sub> = -1 A	2000	_	_	
		h <sub>FE (2)</sub>	V <sub>CE</sub> = -2 V, I <sub>C</sub> = -3 A	1000	_	_	
Collector-emitter saturation voltage		V <sub>CE (sat)</sub>	$I_C = -2 \text{ A}, I_B = -4 \text{ mA}$	_	_	-1.5	V
Base-emitter saturation voltage		V <sub>BE (sat)</sub>	$I_C = -2 \text{ A}, I_B = -4 \text{ mA}$	_	_	-2.0	V
Switching time	Turn-on time	t <sub>on</sub>	OUTPUT  B2  IN  PUT B1  W  OUTPUT  CO  O  O  O  O  O  O  O  O  O  O  O  O	_	0.30	_	
	Storage time	t <sub>stg</sub>			0.60		μs
	Fall time	t <sub>f</sub>	20 μs $V_{CC} = -30 \text{ V}$ $-I_{B1} = I_{B2} = 6 \text{ mA, DUTY CYCLE} \le 1\%$		0.25	_	

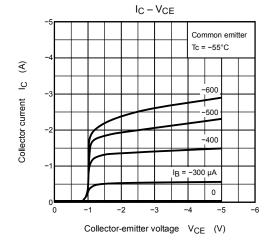
### Marking

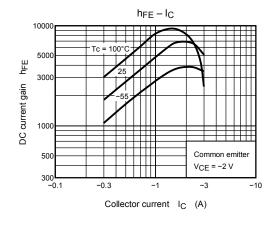


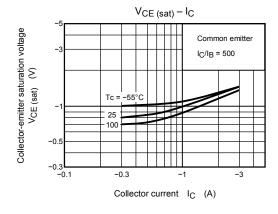
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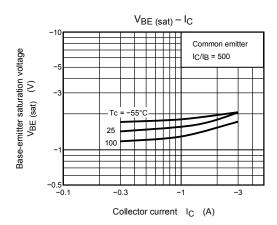


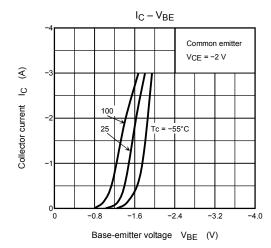


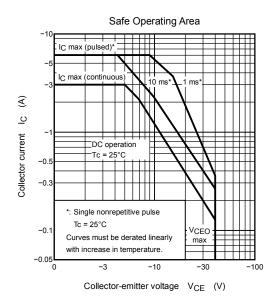


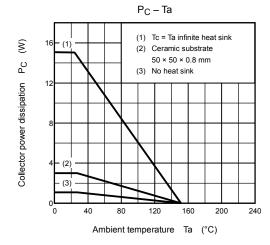












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